

OVERVIEW

The SM8580AM is a real-time clock IC based on a 32.768 kHz crystal oscillator, which features a 4-bit parallel interface for communication with an external microcontroller.

It comprises second-counter to year-counter clock and calendar circuits that feature automatic leap-year adjustment up to year 2099, alarm and timer interrupt functions, clock counter change detect functions, ± 30 -second correction function, time error correction function, and built-in temperature sensor.

The 4-bit parallel interface is compatible with general-purpose SRAM over a high-speed bus.

FEATURES

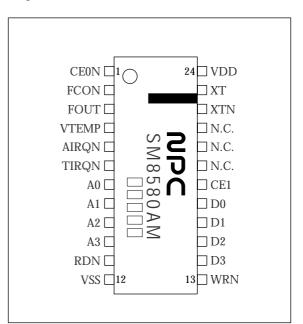
- High-speed bus 4-bit parallel interface
- Date, day, hour, minute, and second-counter presettable alarm interrupt
- 1/4096 seconds to 255 minutes presettable interval timer interrupt function
- 2 software-maskable alarm and timer interrupt outputs
- Clock counter change detect functions
- 4-digit western calendar display
- Automatic leap year correction up to year 2099
- \pm 30-second adjust function
- -195 to +192 ppm time error correction range
- Built-in temperature sensor (analog voltage output)
- 2.4 to 5.5V interface voltage range
- 1.6 to 5.5V clock voltage range
- 0.6µA/3V (typ) current consumption

ORDERING INFORMATION

Device	Package		
SM8580AM	24-pin SSOP		

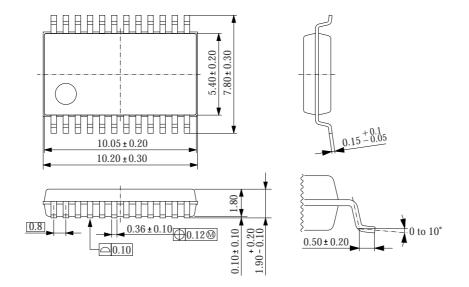
PINOUT

(Top view)

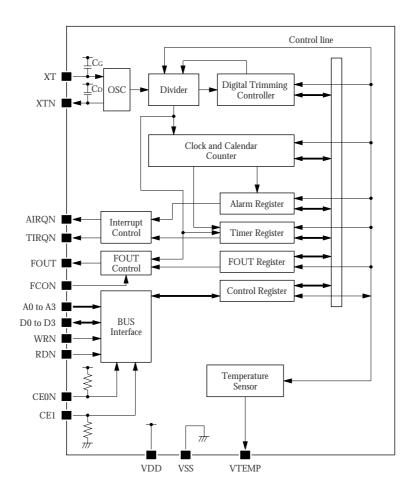


PACKAGE DIMENSIONS

(Unit: mm) **24-pin SSOP**



BLOCK DIAGRAM



PIN DESCRIPTION

Number	Name	I/0	Function ¹
1	CEON	I	Chip enable 0 input with built-in pull-up resistor. The SM8580AM can be accessed when CE0N is LOW and CE1 is HIGH.
2	FCON	I	FOUT output frequency select control input (when CE1 is HIGH). 32.768kHz fixed frequency output when FCON is LOW. Output frequency determined by bit FD when FCON is HIGH (when FE bit is 1). Note that a HIGH-level voltage should be applied to FCON to avoid unwanted 32.768kHz output during backup.
3	FOUT	0	Frequency set register, frequency output (CMOS output)
4	VTEMP	0	Temperature voltage output (analog output)
5	AIRQN	0	Alarm interrupt output (N-channel open-drain output)
6	TIRQN	0	Timer interrupt output (N-channel open-drain output)
7	A 0	I	
8	A1	I	Address inputs. Connect to the microcontroller address bus.
9	A2	I	The selected register address is input on this bus when accessing the SM8580AM (positive logic).
10	A 3	I	
11	RDN	I	Read strobe input. Data can be read from SM8580AM when RDN is LOW and WRN is HIGH. An error will occur if both RDN and WRN are simultaneously LOW.
12	VSS	-	Ground
13	W R N	I	Write strobe input. Data can be written to SM8580AM when RDN is HIGH and WRN is LOW. An error will occur if both RDN and WRN are simultaneously LOW.
14	D 3	I/O	
15	D2	I/O	Data bus input/outputs.
16	D1	I/0	Connect to the microcontroller data bus.
17	D 0	I/O	
18	CE1	I	Chip enable 1 input with built-in pull-down resistor. The SM8580AM can be accessed when CEON is LOW and CE1 is HIGH. FOUT is in output mode when CE1 is HIGH, regardless of the state of CEON. FOUT is high impedance when CE1 is LOW.
19	NC	-	No connection
20	NC	-	No connection
21	NC	-	No connection
22	XTN	0	Oscillator output, with built-in oscillator capacitance C _D
23	XT	I	Oscillator output, with built-in oscillator capacitance ${\rm C}_{\rm G}$
24	V D D	-	Supply

1. Connect a $0.1 \mu F$ capacitor between VDD and VSS.

FOUT Output and SM8580AM Access Relationship

CEON	CE1	FCON	FE bit	FOUT output	SM8580AM accessible
HIGH	LOW	×	×	High impedance	No
LOW	LOW	×	×	High impedance	No
			0	32.768kHz output	No
HIGH	нідн	LOW	1	32.768kHz output	No
пісп	пібп	HIGH	0	High impedance	No
		HIGH	1	FD bit select frequency output	No
		LOW	0	32.768kHz output	Yes
LOW	шсц	LOW	1	32.768kHz output	Yes
LUW	LOW HIGH -		0	High impedance	Yes
			1	FD bit select frequency output	Yes

SPECIFICATIONS

Absolute Maximum Ratings

 $V_{SS} = 0 V$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V _{DD}		-0.3 to 7.0	V
Input voltage range	V _{IN}	All inputs, D0 to D3	$V_{SS} - 0.3$ to V_{DD} + 0.3	V
Output voltage renge	V _{OUT1}	TIRQN, AIRQN	V _{S S} - 0.3 to 8.0	V
Output voltage range	V _{OUT2}	FOUT, D0 to D3, VTEMP	V _{SS} – 0.3 to V _{DD} + 0.3	V
Storage temperature range	T stg		-55 to 125	°C

Recommended Operating Conditions

 $V_{SS} = 0 V$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V _{DD}		2.4 to 5.5	V
Clock supply voltage range	V _{CLK}		1.6 to 5.5	V
Operating temperature range	T _{opr}		-40 to 85	°C

DC Electrical Characteristics

$V_{SS} = 0V, V_{DD} =$	$= 1.6$ to 5.5V, T_a	$= -40$ to 85° C	unless otherw	ise noted
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Parameter	Symbol		Condition	Rating			Unit
Parameter	Symbol		conution		typ	max	Unit
Current consumption 1	I _{DD1}	V _{DD} = 5V	$CEON = RDN = WRN = V_{DD}$	-	1.0	2.0	μA
Current consumption 2	I _{DD2}	V _{DD} = 3V	A0 to A3 = D0 to D3 = V_{DD} or V_{SS} , CE1 = FCON = V_{SS} , AIRQN = TIRQN = FOUT = V_{DD} , VTEMP output OFF (TEMP bit = 0)	-	0.6	1.0	μA
Current consumption 3	I _{DD3}	$V_{DD} = 5V$	Ta = 25°C,	-	50	75	μA
Current consumption 4	I _{DD4}	V _{DD} = 3V	$\begin{array}{l} CE0N = RDN = WRN = V_{DD},\\ A0 \text{ to } A3 = D0 \text{ to } D3 = V_{DD} \text{ or } V_{SS},\\ CE1 = FCON = V_{SS},\\ AIRQN = TIRQN = FOUT = V_{DD},\\ VTEMP \text{ output ON} (TEMP \text{ bit} = 1) \end{array}$	-	40	60	μA
Current consumption 5	I _{DD5}	$V_{DD} = 5V$	$CEON = CE1 = RDN = WRN = V_{DD}$	-	3.0	7.5	μA
Current consumption 6	I _{DD6}	V _{DD} = 3V	A0 to A3 = D0 to D3 = V_{SS} , FCON = V_{SS} , AIRQN = TIRQN = FOUT = VTEMP = Hi-Z, VTEMP output OFF (TEMP bit = 0), FOUT = 32kHz output, C _L = 0pF	-	1.7	4.5	μA
Current consumption 7	I _{DD7}	$V_{DD} = 5V$	$CEON = CE1 = RDN = WRN = V_{DD}$	-	8.0	20	μA
Current consumption 8	I _{DD8}	V _{DD} = 3V	A0 to A3 = D0 to D3 = V_{SS} , FCON = V_{SS} , AIRQN = TIRQN = FOUT = VTEMP = Hi-Z, VTEMP output OFF (TEMP bit = 0), FOUT = 32kHz output, C _L = 30pF	-	5.0	12	μA
HIGH-level input voltage 1	V _{IH1}	V _{DD} = 4.5 t	V _{DD} = 4.5 to 5.5V,		-	V _{DD} + 0.3	V
LOW -level input voltage 1	V _{IL1}	CEON, FCON, RDN, WRN, A0 to A3, D0 to D3		$V_{SS} - 0.3$	-	0.8	V
HIGH-level input voltage 2	V _{IH2}	V _{DD} = 2.4 to 3.6V, CEON, FCON, RDN, WRN, A0 to A3, D0 to D3		0.8V _{DD}	-	$V_{DD} + 0.3$	V
LOW -level input voltage 2	V _{IL2}			$V_{SS} - 0.3$	-	0.2V _{DD}	V
HIGH-level input voltage 3	V _{IH3}	V _{DD} = 1.6 t	V _{DD} = 1.6 to 5.5V,		-	V _{DD} + 0.3	V
LOW -level input voltage 3	V _{IL3}	CEI		$V_{SS} - 0.3$	-	0.2V _{DD}	V
Input leakage current	I _{LEAK}	CEON = V _D FCON = RI	_{ID} , CE1 = V _{SS} , DN = WRN = A0 to A3 = V _{DD} or V _{SS}	-0.5	-	0.5	μA
Pull-up resistance 1	R _{UP1}	$V_{DD} = 5V$	- CEON = V _{SS}	75	150	300	kΩ
Pull-up resistance 2	R _{UP2}	$V_{DD} = 3V$		150	300	600	kΩ
Pull-down resistance 1	R _{DWN1}	$V_{DD} = 5V$	- CE1 = V _{DD}	20	40	80	MΩ
Pull-down resistance 2	R _{DWN2}	$V_{DD} = 3V$		42.5	85	170	MΩ
Pull-down resistance 3	R _{DWN3}	$V_{DD} = 5V$	- CE1 = 0.5V	30	60	120	kΩ
Pull-down resistance 4	R _{DWN4}	$V_{DD} = 3V$	$\neg CET = 0.5V$	55	110	220	kΩ
HIGH-level output voltage 1	V _{OH1}	$V_{DD} = 5V$		4.5	-	5.0	V
HIGH-level output voltage 2	V _{OH2}	$V_{DD} = 3V$	- I _{OH} = —1mA, D0 to D3, FOUT	2.0	-	3.0	V
HIGH-level output voltage 3	V _{OH3}	$V_{DD} = 3V$	Ι _{ΟΗ} = -100μΑ, D0 to D3, FOUT	2.9	-	3.0	V
LOW -level output voltage 1	V _{OL1}	$V_{DD} = 5V$		0	-	0.5	V
LOW -level output voltage 2	V _{OL2}	$V_{DD} = 3V$	- I _{OL} = 1mA, D0 to D3, FOUT	0	-	0.8	V
LOW -level output voltage 3	V _{OL3}	$V_{DD} = 3V$	I _{OL} = 100µA, D0 to D3, FOUT	0	-	0.1	V
LOW -level output voltage 4	V _{OL4}	V _{DD} = 5V		0	-	0.25	V
LOW -level output voltage 5	V _{OL5}	$V_{DD} = 3V$	- I _{OL} = 1mA, AIRQN, TIRQN	0	-	0.4	V
Output leakage current	I _{OZ}	D0 to D3, A	IRQN, TIRQN, FOUT, $V_{OUT} = V_{DD}$ or V_{SS}	-0.5	-	0.5	μA

Terminal Capacitance Characteristics

 $Ta = 25^{\circ}C, f = 1MHz$

Parameter	Symbol	Condition -		Unit		
Parameter	3911001		min	typ	max	UIII
Address input capacitance	C _{ADD}	A0 to A3	-	-	8	рF
Data output capacitance	C _{DATA}	D0 to D3	-	-	15	рF

Oscillator Characteristics

 $T_a = 25^{\circ}C$, Seiko Epson C-002SH crystal ($C_I = 30k\Omega$, $C_L = 10pF$) unless otherwise noted

Parameter	Symbol	Symbol Condition		Rating			
Palameter	Symbol Condition		min	typ	max	Unit	
Oscillator start time	t _{S TA}	V _{DD} = 1.6 V	-	-	3.0	S	
Oscillator stop voltage	V _{STO}		-	-	1.5	V	
Frequency voltage characteristic	f/V	V _{DD} = 1.6 to 5.5V	-2	-	+ 2	ppm/V	
Frequency accuracy	ε _{IC}	V _{DD} = 3.0V	-20	-	+20	ppm	
Input capacitance	C _G	V _{DD} = 3.0V	-	15	-	рF	
Output capacitance	CD	V _{DD} = 3.0V	-	10	-	рF	

AC Characteristics (1)

 $V_{SS} = 0V$, $T_a = -40$ to 85°C unless otherwise noted

Parameter	Symbol	Condition		Unit		
			min	max	min	UIII
FOUT duty	Duty	$V_{DD} = 5V \pm 10\%$	40	-	60	%
		$V_{DD} = 3V \pm 10\%$	40	-	60	%
Oscillator failure detection time	tosc	$V_{DD} = 5V \pm 10\%$	10	-	-	m s
		$V_{DD} = 3V \pm 10\%$	10	-	-	ms

AC Characteristics (2)

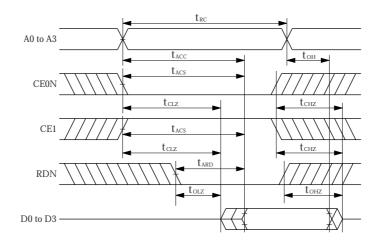
 V_{DD} = 2.4 to 3.6V, V_{SS} = 0V, Ta = -40 to 85°C, inputs V_{I} = 0.5 V_{DD} , outputs V_{O} = 0.5 V_{DD} output load capacitance C_{L} = 100pF (t_{ACC}, t_{ACS}, t_{ARD})

Parameter	Symbol	R	Rating		
	Symbol	min	max	– Unit	
Read cycle time	t _{R C}	150	-	ns	
Address access time	tacc	-	150	ns	
CE access time	tacs	-	150	ns	
RD access time	t _{ARD}	-	100	ns	
CE output set time	t _{CLZ}	5	-	ns	
CE output floating	t _{c hz}	-	60	ns	
RD output set time	t _{olz}	5	-	ns	
RD output floating	t _{ohz}	-	60	ns	
Output hold time	t _{он}	10	-	ns	
Write cycle time	t _{w c}	150	-	ns	
Chip select time	t _{c w}	140	-	ns	
Address valid to end-of-write	t _{AW}	140	-	ns	
Address setup time	t _{AS}	0	-	ns	
Address hold time	t _{W R}	0	-	ns	
Write pulsewidth	t _{W P}	130	-	ns	
Input data set time	t _{DW}	80	-	ns	
Input data hold time	t _{D H}	0	-	ns	

 V_{DD} = 4.5 to 5.5V, V_{SS} = 0V, Ta = -40 to 85°C, inputs V_{I} = 0.5 V_{DD} , outputs V_{O} = 0.5 V_{DD} output load capacitance C_{L} = 100pF (t_{ACC}, t_{ACS}, t_{ARD})

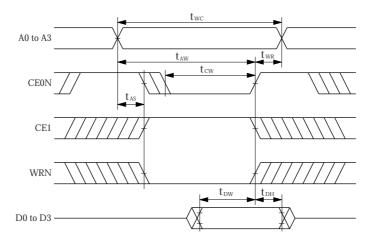
Parameter	Symbol	R	Rating		
Parameter	Symbol	min	max	– Unit	
Read cycle time	t _{RC}	85	-	ns	
Address access time	tacc	-	85	ns	
CE access time	t _{ACS}	-	85	ns	
RD access time	t _{ARD}	-	45	ns	
CE output set time	t _{clz}	3	-	ns	
CE output floating	t _{CHZ}	-	30	ns	
RD output set time	tolz	3	-	ns	
RD output floating	t _{OHZ}	-	30	ns	
Output hold time	t _{он}	5	-	ns	
Write cycle time	t _{w c}	85	-	ns	
Chip select time	t _{c w}	70	-	ns	
Address valid to end-of-write	t _{AW}	70	-	ns	
Address setup time	t _{AS}	0	-	ns	
Address hold time	t _{w R}	0	-	ns	
Write pulsewidth	t _{W P}	65	-	ns	
Input data set time	t _{DW}	35	-	ns	
Input data hold time	t _{DH}	0	-	ns	

Data read

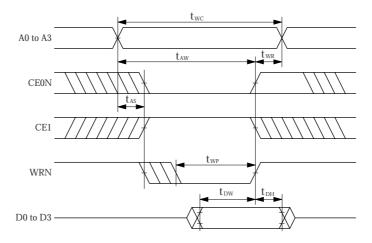


Data write

CE control



WR control



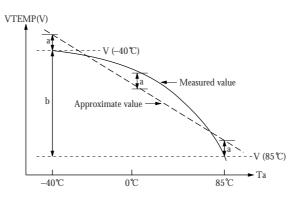
Temperature Sensor

Parameter	Symbol	Condition	Condition			Unit
Parameter	Symbol			max	min	Unit
Temperature sensor output voltage	V _{OUT}	Ta = 25°C, VSS reference output voltage, V _{DD} = 2.7 to 5.5V, VTEMP	-	1.470	-	V
Output accuracy	T _{ACR}	Ta = 25°C	-	-	±5	°C
Temperature sensitivity ¹	V _{SE}	-40 °C \leq Ta \leq 85 °C , V $_{DD}$ = 2.7 to 5.5V	-7.3	-7.8	-8.3	mV/°C
Linearity ²	ΔNL	-40°C \leq Ta \leq 85°C , V _{DD} = 2.7 to 5.5V	-	-	±2.0	%
Temperature detection range	T _{OPR}	$\Delta \text{NL} \le \pm 2.0\%$, V _{DD} = 2.7 to 5.5V	-40	-	85	°C
Output resistance ³	R ₀	Ta = 25°C, V _{DD} = 2.7 to 5.5V, VTEMP	-	1.0	3.0	kΩ
Output load capacitance	CL	V _{DD} = 2.7 to 5.5V	-	-	100	рF
Output load resistance	RL	V _{DD} = 2.7 to 5.5V	500	-	-	kΩ
Response time	t _{RSP}	V_{DD} = 3.0V, R_{L} = 500k Ω , C_{L} = 100pF	-	-	200	μs

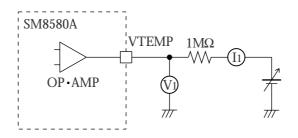
 $V_{SS} = 0V$, $T_a = -40$ to 85°C unless otherwise noted

1. Temperature sensitivity $V_{SE} = (V(85^{\circ}C) - V(-40^{\circ}C)) \div 125 \text{ [mV/}^{\circ}C]$ 2. Linearity $\Delta NL = a \div b \times 100 \text{ [%]}$, where a = maximum deviation between the measured value and the approximated value of VTEMP, and

b = difference between the measured values at temperatures of -40 and $85^{\circ}C$



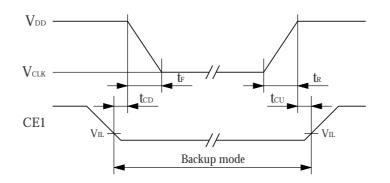
3. Output resistance R_0 = $\Delta V_1 \div \Delta I_1$ [Ω]



Backup Transfer and Return

Parameter ¹	Symbol	Condition		Rating		Unit
Palallelel	Symbol	Condition	min	max	min	Unit
Supply voltage falling edge CE setup time	t _{C D}		0	-	-	μs
Supply voltage fall time	+	$(V_{DD} - V_{CLK}) \le 2.0V$	2	-	-	µs/V
Supply voltage fall time	t _F	$(V_{DD} - V_{CLK}) > 2.0V$	50	-	-	µs/V
Supply voltage rise time	t _R		1	-	-	µs/V
Supply voltage rising edge CE hold time	t _{c u}		0	-	-	μs

1. Before switching the supply, confirm that the chip enable CE1 is LOW and that SM8580AM is deselected.



FUNCTIONAL DESCRIPTION

Register Tables

Bank 0 (clock, calendar registers)

Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
0	Cooped registers	8	4	2	1
1	Second registers	FOS	40	20	10
2	Minuto registers	8	4	2	1
3	Minute registers	#	40	20	10
4	Hour registers	8	4	2	1
5	Hour registers	#	#	20	10
6	Day of week register	#	4	2	1
7	Data na nistana	8	4	2	1
8	Date registers	#	#	20	10
9	Month registers	8	4	2	1
A	Month registers	#	#	#	10
В		8	4	2	1
С	Voar rogistors	80	40	20	10
D	Year registers	800	400	200	100
E		TEST	TEMP	2000	1000
F	Control register	Bank SEL1	Bank SELO	STOP	BUSY/ ADJ

Bank 1 (alarm, FOUT registers)

Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
0	Second registers	8	4	2	1
1	Second registers	AE	40	20	10
2	Minute registers	8	4	2	1
3	willule registers	AE	40	20	10
4	Hour registers	8	4	2	1
5	Hour registers	AE	*	20	10
6	Day of week register	AE	4	2	1
7	Data sasiatasa	8	4	2	1
8	Date registers	AE	*	20	10
9	-	*	*	*	*
A	-	*	*	*	*
В	CE1 control	CTEMP	CDT_ON	*	*
С	FOUT divider set register	#	FD2	FD1	F D O
D	FOUT frequency set register	FE	#	FD4	FD3
E	Alarm control	TEST	TEMP	AF	AIE
F	Control register	Bank SEL1	Bank SELO	STOP	BUSY/ ADJ

Bank 2 (digital correction, timer registers)

Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
0	Digital correction	DT3	DT2	DT1	DTO
1	registers	DT_ON	DT6	DT5	DT4
2	-	#	#	#	#
3	-	#	#	#	#
4	Timer counter set	8	4	2	1
5	registers	128	64	32	16
6	Timer counter	8	4	2	1
7	output registers	128	64	32	16
8	Timer setting	TE	TI/TP	TD1	TDO
9	-	#	#	#	#
A	-	#	#	#	#
В	-	*	*	*	*
С	-	*	*	*	*
D	-	*	*	*	*
E	Timer control	TEST	TEMP	TF	TIE
F	Control register	Bank SEL1	Bank SELO	STOP	BUSY/ ADJ

- All bits in register F and bits 2 to 3 in register E are common to all register banks.
- When alarm interrupts are not used, registers 0 to 8 in bank 1 can be used as RAM (total 36 bits).
- When timer interrupts are not used, registers 4 to 5 in bank 2 can be used as RAM (total 8 bits).
- When digital correction is not used, registers 0 to 1 in bank 2 can be used as RAM, excluding bit 3 (DT_ON) in register 1 (total 7 bits).
- The BUSY/ADJ bit function is BUSY when reading, and ADJ when writing.
- The BUSY flag is set to 1 an interval of 244µs before clock counter update timing.
- Registers 6 and 7 in bank 2 are read-only registers, and cannot be written to.
- When power is applied, all register bits are undefined, with the exception of bits FOS, TEST and TEMP. Accordingly, these bits need to be initialized. TEST and TEMP are automatically reset to 0 and FOS is automatically reset to 1 when power is applied.
- Bits marked # are all read-only bits fixed to 0. These bits cannot be written to.
- Bits marked * can be used as RAM bits.

Control Registers (All Banks, Register E (bits 2, 3) and F)

Bank	Address	Bit 3	Bit 2	Bit 1	Bit 0
0, 1, 2	E	TEST	TEMP		
0, 1, 2	F	Bank SEL1	Bank SELO	STOP	BUSY/ADJ

TEST bit

Factory test bit.

This bit should be set to 0. Take care when writing to other E register bits not to accidentally write 1 to the TEST bit. Automatically resets to 0 when power (VDD) is applied.

TEMP bit

When set to 1, it enables the temperature sensor voltage output on pin VTEMP. When set to 0, VTEMP is high impedance. Automatically resets to 0 when power is applied.

Bank SEL bits

Bank select bits for read/write operations.

Bank SEL1	Bank SELO	Accessed bank
0	0	Bank 0
0	1	Bank 1
1	0	Bank 2
1	1	Bank 1

STOP bit

When set to 1, the clock 32Hz frequency divider counter stops and is reset. When set to 0, the clock restarts.

BUSY/ADJ bit

This bit functions as a BUSY function in read mode, and as an ADJ function in write mode.

• ADJ function (±30 seconds adjust bit) Second registers are reset to 00 and minute registers not incremented when the clock counter is reset and the second registers are currently 00 to 29.

Second registers are reset to 00 and minute registers are incremented when the clock counter is reset and the second registers are currently 30 to 59.

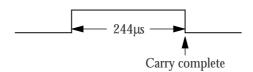
The ADJ bit is automatically reset to 0 a maximum of $244\mu s$ after it is set to 1, and thus the register should not be written to during this $244\mu s$ interval.

• BUSY function (second registers increment or ±30 seconds adjust busy indicator bit)

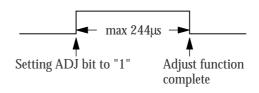
When BUSY is 1, the counters are being updated (incremented or reset). To read or write to clock and calendar registers, the BUSY flag has to be 0. If reading data when BUSY is set to 1, there is a possibility that incorrect (intermediate) data will be output.

BUSY is set to 1 under the following two circumstances.

Normal seconds digit carry



±30 seconds digit adjust (when ADJ is set to 1)



Function operation table

Bit		Function				
STOP	ADJ	Clock	Timer	Alarm	FOUT	
0	0	Operating	Operating ³	Operating	Operating ⁶	
0	1	Adjust ¹	Operating ⁴	Operating	Operating ⁷	
1	0	Stopped	Operating/stopped ⁵	Stopped	Operating/stopped ⁸	
1	1	Stopped/adjust ²	Operating/stopped ⁵	Stopped	Operating/stopped ⁸	

1. ±30 seconds adjust function

2. The clock stops, and the ± 30 seconds adjust function operates.

3. If the timer source clock frequency is \leq 1Hz, the timer cycle changes when the digital correction function is used. If the timer source clock frequency is \geq 64Hz, the timer cycle is not affected when the digital correction function is used.

4. If the timer source clock frequency is \leq 1Hz, the timer cycle changes. If the timer source clock frequency is \geq 64Hz, the timer cycle does not change.

5. If the timer source clock frequency is \leq 1Hz, the timer is stopped. If the timer source clock frequency is \geq 64Hz, the timer operates.

6. If the FOUT source clock frequency is \leq 1Hz, the cycle changes when the digital correction function is used. If the FOUT source clock frequency is \geq 32Hz, the cycle is not affected when the digital correction function is used.

- 7. If the FOUT source clock frequency is \leq 1Hz, the cycle changes. If the FOUT source clock frequency is \geq 32Hz, the cycle does not change.
- 8. If the FOUT source clock frequency is \leq 1Hz, the timer is stopped. If the FOUT source clock frequency is \geq 32Hz, the timer operates.

Clock and Calendar Registers (Bank 0, Registers 0 to E)

Clock counters (registers 0 to 5)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
	0	Second registers	8	4	2	1
	1	Second registers	FOS	40	20	10
0	2	Minute registere	8	4	2	1
U	3	Minute registers		40	20	10
	4	Hour registers	8	4	2	1
	5	Hour registers			20	10

 Data in these registers is interpreted in BCD format. For example, if the seconds registers 1 and 0 contain 0101 1001, then the contents are interpreted as the value 59 seconds. Hour register contents are values expressed in 24hour mode.

FOS (oscillator failed detect bit (register 1, bit 3))

The FOS bit is the oscillator failure flag. It indicates that the oscillator has stopped due to supply voltage reduction during operation. It is set to 1 when the oscillator stops, and remains 1 until reset

by writing 0 to FOS. It is not affected by the function of other bits. A 1 is written to FOS when power is applied.

Day-of-week counter (register 6)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
0	6	Day of week register		4	2	1

The day-of-week register contains values representing the day of the week as shown in the following table.

Bit 2	Bit 1	Bit 0	Weekday	
0	0	0	Sunday	
0	0	1	Monday	
0	1	0	Tuesday	
0	1	1	Wednesday	
1	0	0	Thursday	
1	0	1	Friday	
1	1	0	Saturday	

Calendar registers (registers 7 to E)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
	7	Data registera	8	4	2	1
	8	Date registers			20	10
	9	Month registers	8	4	2	1
0	A	Month registers				10
U	В		8	4	2	1
	С	Voor rogistors	80	40	20	10
	D	Year registers	800	400	200	100
	E		TEST	TEMP	2000	1000

• Registers B to E are 4 digits forming the western calendar year.

• Leap-year adjustment is automatic for years 1901 to 2099.

Alarm Registers (Bank 1, Registers 0 to 8, E)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
1	E	Alarm control			AF	AIE

■ AF bit (alarm flag)

The AF bit is set to 1 when an alarm event is occurred, when the settings in the alarm set registers (bank 1, registers 0 to 8) match the settings in the day, clock and calendar registers (bank 0, registers 0 to 8). The AF bit remains 1 until reset by writing 0 to AF. A logic 1 cannot be written to AF.

■ AIE bit (alarm interrupt enable)

This bit enables the output on AIRQN when an alarm interrupt is occurred. If the AIE is not set to 1, then no output occurs even if the AF bit is set to 1. The AIRQN output is high impedance when AIE is set to 0.

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
	0	Second registers	8	4	2	1
	1	Second registers	AE	40	20	10
	2	Minute registers	8	4	2	1
	3		AE	40	20	10
1	4	Hour registers	8	4	2	1
	5	nour registers	AE	*	20	10
	6	Day of week register	AE	4	2	1
	7	Date registers	8	4	2	1
	8	Date registers	AE	*	20	10

Alarm set registers (registers 0 to 8)

Alarm control register (register E)

- These registers set the alarm time and date.
- When the corresponding bank 0 registers match these bank 1 registers, an alarm event occurs and AIRQN goes LOW if AIE is set to 1.
- An alarm can be set for date, day-of-week, hour, minute, and second. Each of these have a corresponding AE (alarm enable) bit which allows easy combination to create alarm events every second, every minute, hourly, daily, and weekly alarms.

Day-of-week alarm bits (register 6)

 The day-of-week register contains values representing the day of the week as shown in the following table.

- Note that alarms cannot be set for multiple days within the same week (such as an alarm on Mondays and Fridays only).
- When an AE bit is set to 0, the relevant register and corresponding bank 0 register are compared. When an AE bit is set to 1, the data is disregarded and all bits considered as "don't care" bits.

Bit 2	Bit 1	Bit 0	Weekday		
0	0	0	Sunday		
0	0	1	Monday		
0	1	0	Tuesday		
0	1	1	Wednesday		
1	0	0	Thursday		
1	0	1	Friday		
1	1	0	Saturday		

Timer Registers (Bank 2, Registers 4 to 8, E)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
2	8	Timer setting	TE	TI/TP		
2	E	Timer control			TF	TIE

Timer control registers (registers 8, E)

■ TE bit (timer enable)

Timer countdown stop/start control bit.

When set to 1, the timer starts counting down. When set to 0 during countdown, the timer stops.

- TF bit (timer flag) The timer flag is set to 1 when the timer counter counts down to zero, occurring a timer event. It is held at 1 until 0 is written to this bit. A 1 cannot be written to TF.
- TIE bit (timer interrupt enable) This bit enables the timer interrupt output on TIRQN when a timer event is occurred. If the TIE is not set to 1, then no output occurs even if the TF bit is set to 1. The TIRQN output is high impedance when TIE is set to 0.
- TI/TP bit (level/periodic interrupt mode select bit) Sets the timer interrupt signal output mode. The SM8580AM supports two timer function modes.

• TI/TP = 0 (level interrupt mode)

When a timer interrupt is occurred, TIRQN goes LOW (if TIE = 1) and TF is set to 1. TIRQN remains LOW and TF is held at 1 until a 0 is written to the TF bit.

The timer operates by counting down until the data is zero, then the TE bit is cleared and the count stops automatically. However, if the timer is started when the TF bit is 1, then the TE bit is not cleared. The timer count register contents remain zero after the count down stops.

- TI/TP = 1 (periodic interrupt mode)
- When a timer interrupt is occurred, TIRQN goes LOW (if TIE = 1) and TF is set to 1. TIRQN subsequently goes high impedance after a fixed interval, but TF is held at 1 until a 0 is written to the TF bit.

The timer operates by counting down until the data is zero, then the timer register data is reloaded automatically after a fixed interval, and the countdown restarts. This mode can be used as a repetitive interval timer.

Timer source clock set register (register 8)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
2	8	Timer setting			TD1	T D O

 The register 8 bits 0 and 1 set the timer source clock to one of four frequencies listed in the following table.

TD1	TDO	Timer source clock
0	0	4096Hz
0	1	64Hz
1	0	1Hz
1	1	1/60Hz (1 minute)

Timer counter set registers (registers 4 to 7)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
	4	Timer counter set registers	8	4	2	1
2	5		128	64	32	16
2	6		8	4	2	1
	7	Timer counter output registers	128	64	32	16

- Registers 4 and 5 set an 8-bit presettable binary down-counter value for the timer interrupt function.
- The value of the count can be determined by reading the values of registers 6 and 7 during the count.
- The presettable binary down-counter is updated when the data is written to registers 4 and 5.
- The data written to registers 4 and 5 are stored and are not changed until replacement data is written.

Timer interrupt function example

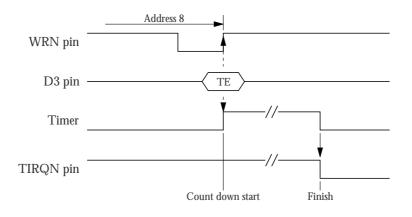
Example of an hourly periodic timer interrupt

This allows these bits to function as RAM bits if the timer interrupt mode is not used (when TIE = 0).

- When TE is set to 1, periodic interrupts are not output on TIRQN, even if registers 4 and 5 are set to zero.
- The timer error once a timer operation is started is a maximum of one cycle of the source clock. Timer operations started and stopped in less than one cycle of the source clock are not counted.

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
	4	Timer counter set registers	1	1	0	0
n	5		0	0	1	1
2	8	Timer set register	TE	1	1	1
	E	Timer control	TEST	TEMP	TF	1

The timer start timing is set up in write mode when the WRN rising edge corresponding to the TE bit occurs, as shown in the following timing diagram.



CE1 Control Register (Bank 1, Register B)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
1	В	CE1 control	СТЕМР	CDT_ON		

- This register determines whether the temperature sensor function and digital correction function in combination with the CE1 input pin. CTEMP determines the temperature sensor operation, and CDT_ON determines the digital correction function operation.
- CTEMP bit

When CTEMP is set to 0, the temperature sensor operates only when the CE1 pin is HIGH.

When CTEMP is set to 1, the temperature sensor operates without any relationship to the CE1 input state.

Note that the temperature sensor operation also depends on the bank 2 TEMP bit to be active.

CDT_ON bit

When CDT_ON is set to 0, the digital correction function operates only when the CE1 pin is HIGH. When CDT_ON is set to 1, the digital correction function operates without any relationship to the CE1 input state.

Note that the digital correction function also depends on the bank 2 DT_ON bit to be active.

• Function operation tables

CE1 pin	CTEMP bit	TEMP bit	Temperature sensor
×	×	0	Not operating
LOW	0	1	Not operating
HIGH	0	1	Operating
LOW	1	1	Operating
HIGH	1	1	Operating

CE1 pin	CDT_ON bit	DT_ON bit	Digital correction
×	×	0	Not operating
LOW	0	1	Not operating
HIGH	0	1	Operating
LOW	1	1	Operating
HIGH	1	1	Operating

Frequency Set Registers (Bank 1, Registers C, D)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
1	С	FOUT divider set register		FD2	FD1	F D O
I	D	FOUT frequency set register	FE		FD4	FD3

■ FD3, FD4 bit

FOUT source clock frequency set bits.

FD4	FD3	Source clock
0	0	32768Hz
0	1	1024Hz
1	0	32Hz
1	1	1Hz

■ FD0 to FD2 bits

Frequency divider set bits for the FOUT source clock set by FD3 and FD4.

FD2	FD1	F D O	Frequency divider ratio	FOUT output duty
0	0	0	1/1	1/2
0	0	1	1/2	1/2
0	1	0	1/3	1/3
0	1	1	1/6	1/2

FD2	FD1	FD0	Frequency divider ratio	FOUT output duty
1	0	0	1/5	1/5
1	0	1	1/10	1/2
1	1	0	1/15	1/3
1	1	1	1/30	1/2

■ FE bit

FOUT frequency signal set by FD0 to FD4 output enable bit.

When FCON is HIGH and FE is set to 1, then the frequency signal set by FD0 to FD4 is output on FOUT. When FE is set to 0, the FOUT output is high impedance.

When FCON is LOW, a standard 32.768kHz signal is output on FOUT without reference to the settings in the C and D registers.

Digital Correction Registers (Bank 2, Registers 0, 1)

Bank	Address	Register	Bit 3	Bit 2	Bit 1	Bit 0
2	0	Digital correction registers	DT3	DT2	DT1	DTO
2	1		DT_ON	DT6	DT5	DT4

- These registers enable and set the level of digital correction applied to oscillator clock. DT_ON enables the correction function, and bits DT0 to DT6 set the level of correction to be applied. This function adjusts the number of 1 second cycles which occur every 10 seconds.
- When digital correction is not used, a 0 should be written to DT_ON to disable correction.
- Correction range and resolution (correction range depends on the frequency)

Correction range	Correction resolution	Correction cycle
—195.20 to +192.15ppm	3.05ppm	10 seconds

DT bits and digital correction (correction value depends on the frequency)

Digital correction bits							Correction	
DT6	DT5	DT4	DT3	DT2	DT1	DTO	(ppm)	
0	1	1	1	1	1	1	+192.15	
0	1	1	1	1	1	0	+189.10	
			\downarrow				\downarrow	
0	0	0	0	0	1	0	+6.10	
0	0	0	0	0	0	1	+3.05	
0	0	0	0	0	0	0	±0.00	
1	1	1	1	1	1	1	-3.05	
1	1	1	1	1	1	0	-6.10	
	\downarrow						\downarrow	
1	0	0	0	0	0	1	-192.15	
1	0	0	0	0	0	0	-195.20	

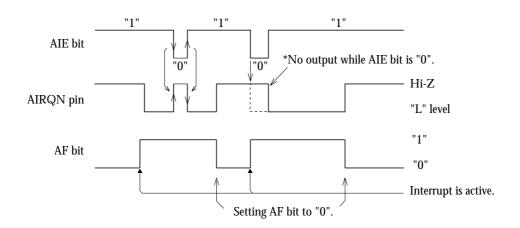
Correction value calculation

- Positive correction (leading time) [DT6:0] = correction ÷ 3.05 (with decimal round-off) Example: for correction of 192.15ppm [DT6:0] = 192.15 ÷ 3.05 = 63₁₀ = 0111111₂
 Negative correction (lagging time) [DT6:0] = 128 + correction ÷ 2.05 (with decimal section)
 - $[DT6:0] = 128 + \text{correction} \div 3.05 \text{ (with decimal round-off)}$ Example: for correction of -158.6ppm $[DT6:0] = 128 + (-158.6 \div 3.05) = 76_{10} =$
 - 1001100_2

INTERRUPT OPERATION

Alarm Interrupt

When AIE is 1 and an alarm event occurs (AF bit is set to 1), AIRQN output goes LOW. If AIE is 0, however, AIRQN is in a high-impedance state. The alarm interrupt is output when a carry from the seconds register to the minute register occurs.

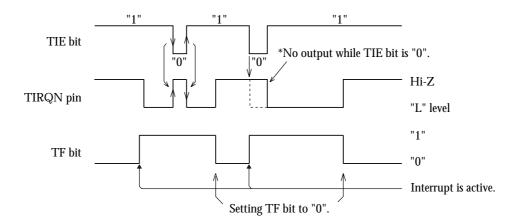


Timer Interrupt

The timer interrupt mode (level interrupt or periodic interrupt) is selected by the setting of TI/TP.

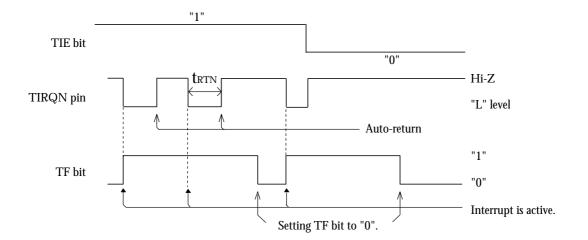
Level interrupt mode (TI/TP = 0)

When TIE is 1 and a timer interrupt event occurs (TF bit is set to 1), TIRQN goes LOW. When TIE is 0, however, TIRQN is in a high-impedance state.

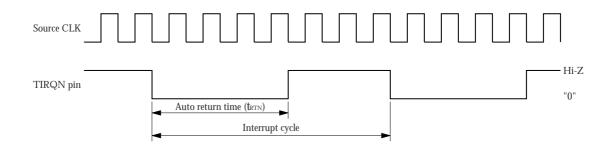


Periodic interrupt mode (TI/TP = 1)

When TIE is 1 and a timer interrupt event occurs (TF bit is set to 1), TIRQN goes LOW. If TIE is 0, however, TIRQN is in a high-impedance state, and the TF bit remains set to 1.



The auto-return time (t_{RTN}), shown in the following figure and table, is determined by the source clock frequency set by register D in bank 1 bits FD3 and FD4.



Source clock	Auto-return time (t _{RTN})
4096Hz	0.122ms
64Hz	7.81ms
1Hz	7.81ms
1/60Hz	7.81ms

APPLICATION NOTES

Setting the Alarm

Alarms can be set for day, weekday, hour, minute, and second. However, it is not possible to set an alarm for more than one weekday.

Note that it is recommended that AF and AIE be set to 0 at the same time to avoid accidental hardware interrupts while setting the alarm. After the alarm data is entered, initialization occurs when AF is again set to 0.

If the interrupt output is not used by setting AIE set to 0, an alarm can still be controlled by software monitoring of the AF bit.

Example 1

To set an alarm for 6pm of the following day:

- Set bits AIE and AF to 0.
- Set the day register AE bit to 1.
- Acquire the current weekday setting from bank 0 register 6, add 1 to the current value (except in

Using the Temperature Sensor

The SM8580AM temperature sensor can be used to monitor the surrounding temperature. The temperature sensor information can then be used to adjust the clock for any temperature variations in the oscillator frequency which affect the accuracy of the clock. One method of utilizing the temperature sensor to adjust timing errors is by using the clock error correction function (digital correction), as described below.

1. Based on the known temperature characteristics of the oscillator crystal, store temperature correction values for various temperatures in an external non-volatile EEPROM.

Monitoring Digital Correction

Using the test mode allows the 64Hz digital correction clock to be output on pin FOUT. The test mode works as follows.

- 1. Apply a HIGH-level on FCON.
- 2. Set the FOUT frequency set register FE bit to 1.
- 3. Set the CE1 control register CDT_ON bit to 1.
- 4. Set correction data in the digital correction register DT0 to DT6 bits, and then set DT_ON to 1.
- 5. Set the bank 2 register C, bit 1 to 1.

the case of Saturday), and write the updated data. Note that the day following $6_{\rm H}$ (Saturday) is $0_{\rm H}$ (Sunday).

- Write $18_{\rm H}$ to the hour alarm register.
- Write $00_{\rm H}$ to the minute alarm register.
- Write $00_{\rm H}$ to the seconds alarm register.
- Set bit AF to 0.
- Set bit AIE to 1.

Example 2

To set an alarm for 6am on every for Sunday:

- Set bits AIE and AF to 0.
- Set the day alarm register AE bit to 1.
- Write $0_{\rm H}$ to the weekday alarm register.
- Write $06_{\rm H}$ to the hour alarm register.
- Write $00_{\rm H}$ to the minute alarm register.
- Write $00_{\rm H}$ to the seconds alarm register.
- Set bit AF to 0.
- Set bit AIE to 1.
- 2. Use an A/D converter, such as in a general-purpose CPU, to convert the VTEMP temperature sensor output voltage into a digital value.
- 3. Use the digital value of the current temperature to access the temperature correction data stored in the EEPROM, and then write the corresponding data into the digital correction registers.

This procedure is useful in implementing a high-accuracy clock function.

- 6. When CE0N is LOW and CE1 is HIGH and the test mode set register TEST bit is set to 1, the digital correction cycle changes from 10 seconds to 1/64 seconds, and the clock output on FOUT is the 64Hz clock after timing correction. The output is the corrected timing for the set digital correction value corresponding to a 64Hz clock × 64[ppm]. Measuring this output provides a quick method for monitoring the digital correction function.
- 7. When CE0N goes HIGH, the TEST bit is reset to 1 and test mode is released.

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